

Taiwan Semiconductor

16A, 50V - 600V Super Fast Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Low forward voltage drop
- Ideal for automated placement
- High current capability
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- DC to DC converter
- Automotive application
- Car lighting
- Snubber
- Freewheeling application

MECHANICAL DATA

- Case: TO-263AB (D²PAK)
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 1.41g (approximately)

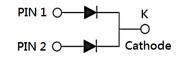
KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _F	16	А		
V _{RRM}	50 - 600	V		
I _{FSM}	125	А		
T _{J MAX}	150	°C		
Package	TO-263AB (D ² PAK)			
Configuration	Dual dies			



OHS HALOGEN



TO-263AB (D²PAK)



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)										
PARAMETER	SYMBOL	SFS 1601	SFS 1602	SFS 1603	SFS 1604	SFS 1605	SFS 1606	SFS 1607	SFS 1608	UNIT
		GH	GH	GH	GH	GH	GH	GH	GH	
Marking code on the device		SFS 1601G	SFS 1602G	SFS 1603G	SFS 1604G	SFS 1605G	SFS 1606G	SFS 1607G	SFS 1608G	
Repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Reverse voltage, total rms value	V _{R(RMS)}	35	70	105	140	210	280	350	420	V
Forward current	I _F	16				Α				
Surge peak forward current, 8.3ms single half sine wave superimposed on rated load	I _{FSM}	-sм 125				A				
Junction temperature	T _J -55 to +150			°C						
Storage temperature	T _{STG}	T _{STG} -55 to +150			°C					



THERMAL PERFORMANCE					
PARAMETER	SYMBOL	ТҮР	UNIT		
Junction-to-case thermal resistance	R _{eJC}	2.5	°C/W		

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)						
PARAMETER		CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage	SFS1601GH SFS1602GH SFS1603GH SFS1604GH	L 94 T 25%C	V _F	-	0.975	V
Forward voltage per diode ⁽¹⁾	SFS1605GH SFS1606GH	I _F = 8A, I _J = 25°C		-	1.300	V
	SFS1607GH SFS1608GH			-	1.700	V
Reverse current @ rated V_R per diode ⁽²⁾		$T_J = 25^{\circ}C$		-	10	μA
		T _J = 125°C	I _R	-	400	μA
lunction conscitutos	SFS1601GH SFS1602GH SFS1603GH SFS1604GH			80	-	pF
Junction capacitance	SFS1605GH SFS1606GH SFS1607GH SFS1608GH	1MHz, V _R = 4.0V	CJ	60	-	pF
Reverse recovery time		$I_F = 0.5A, I_R = 1.0A$ $I_{rr} = 0.25A$	t _{rr}	-	35	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION					
ORDERING CODE ⁽¹⁾	PACKAGE	PACKING			
SFS16xGH	TO-263AB (D ² PAK)	800 / Tape & Reel			

Notes:

1. "x" defines voltage from 50V(SFS1601GH) to 600V(SFS1608GH)



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

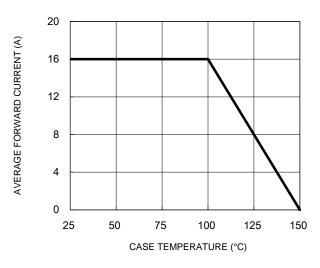


Fig.1 Forward Current Derating Curve

Fig.3 Typical Reverse Characteristics

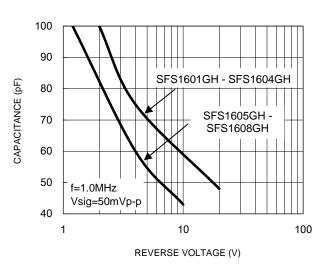
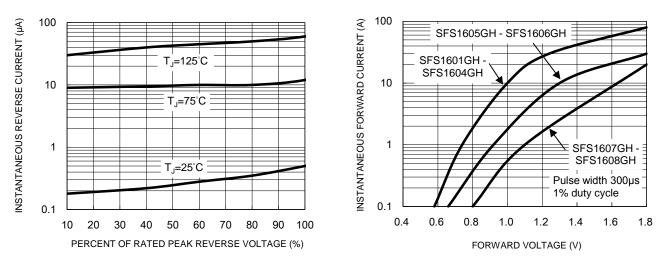


Fig.2 Typical Junction Capacitance





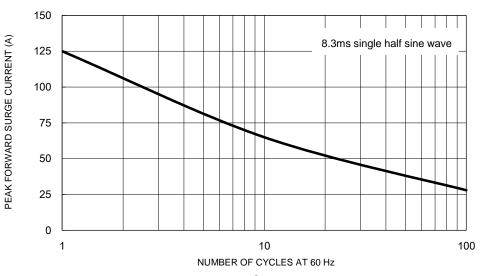


Fig.5 Maximum Non-Repetitive Forward Surge Current

Version: A2103



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CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$

50Ω 10Ω - trr 🗕 NONINDUCTIVE NONINDUCTIVE ~~~ ~~~ +0.5A (-) ± DUT • (+) 50Vdc PULSE 0 GENERATOR = (approx) -0.25A (NOTE 2) (-) IΩ OSCILLOSCOPE 6 (+) (NOTE 1) -1.0A NOTES: 1. Rise Time=7ns max. Input Impedance= ≐ 1 megohm 22pf 2. Rise Time=10ns max. Sourse Impedance= 50 ohms

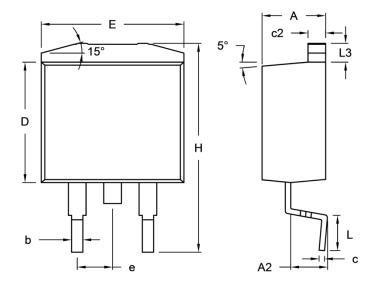
Fig.6 Reverse Recovery Time Characteristic and Test Circuit Diagram



SFS1601GH – SFS1608GH Taiwan Semiconductor

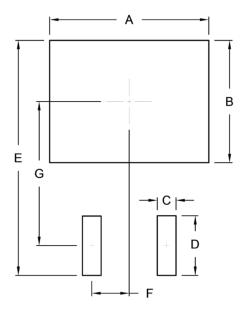
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM. Unit ((mm)	Unit ((inch)	
	Min.	Max.	Min.	Max.	
A	4.44	4.70	0.175	0.185	
A2	2.03	2.79	0.080	0.110	
b	0.68	0.94	0.027	0.037	
с	0.36	0.53	0.014	0.021	
c2	1.14	1.40	0.045	0.055	
D	8.25	9.25	0.325	0.364	
E	-	10.50	-	0.413	
е	2.41	2.67	0.095	0.105	
н	14.60	15.88	0.575	0.625	
L	2.29	2.79	0.090	0.110	
L3	1.14	1.40	0.045	0.055	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
A	10.80	0.425
В	8.30	0.327
С	1.27	0.050
D	4.05	0.159
E	15.95	0.628
F	2.54	0.100
G	9.775	0.385

MARKING DIAGRAM



P/N	= Marking Code
G	= Green Compound
YWW	= Date Code
F	= Factory Code



SFS1601GH - SFS1608GH

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